International

SCHOTTKY RECTIFIER

10BQ100PbF

1 Amp

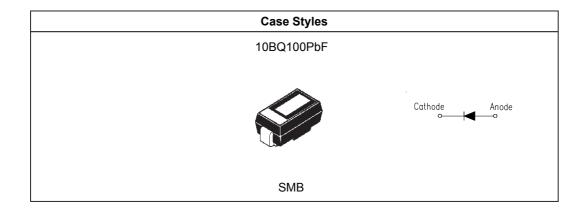
Major Ratings and Characteristics

Characteristics	Value	Units
I _{F(AV)} Rectangular waveform	1.0	A
V _{RRM}	100	V
I_{FSM} @ tp = 5 µs sine	780	А
V _F @1.0 Apk, T _J =125°C	0.62	V
T _J range	- 55 to 175	°C

Description/ Features

The 10BQ100PbF surface-mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free ("PbF" suffix)



Document Number: 94114

10BQ100PbF

Bulletin PD-20786 rev. A 07/04

International **IOR** Rectifier

Voltage Ratings

Part number	10BQ100PbF
V _R Max. DC Reverse Voltage (V)	400
V _{RWM} Max. Working Peak Reverse Voltage (V)	100

Absolute Maximum Ratings

	Parameters	10BQ	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current	1.0	A	50% duty cycle @ $T_L = 152 \degree C$,	rectangular wave form
I _{FSM}	Max. Peak One Cycle Non-Repetitive	780	А	5µs Sine or 3µs Rect. pulse	Following any rated load condition and
	Surge Current	38		10ms Sine or 6ms Rect. pulse	with rated V _{RRM} applied
E _{AS}	Non-Repetitive Avalanche Energy	1.0	mJ	$T_{J} = 25 ^{\circ}C, I_{AS} = 0.5A, L = 8mH$	
I _{AR}	Repetitive Avalanche Current	0.5	A	Current decaying linearly to zer Frequency limited by T_J max. V	o in 1 µsec ∕a = 1.5 x Vr typical

Electrical Specifications

	Parameters	10BQ	Units		Conditions
V _{FM}	Max. Forward Voltage Drop (1)	0.78	V	@ 1A	T ₁ = 25 °C
	* See Fig. 1	0.89	V	@ 2A	1 _J = 25 C
		0.62	V	@ 1A	T, = 125 °C
		0.72	V	@ 2A	1 _J 120 0
I _{RM}	Max. Reverse Leakage Current (1)	0.5	mA	T _J = 25 °C	V_{p} = rated V_{p}
	* See Fig. 2	1	mA	T _J = 125 °C	V _R - lated V _R
CT	Typical Junction Capacitance	42	pF	$V_R = 5V_{DC}$, (test signal range 100kHz to 1MHz) 25°C	
L _s	Typical Series Inductance	2.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Volatge Rate of Charge	10000	V/ µs		
	(Rated V _R)				

(1) Pulse Width < 300 μ s, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters	10BQ	Units	Conditions
TJ	Max. Junction Temperature Range(*)	- 55 to 175	°C	
T _{stg}	Max. Storage Temperature Range	- 55 to 175	°C	
R _{thJL}	Max. Thermal Resistance Junction to Lead (**)	36	°C/W	DC operation
R _{thJA}	Max. Thermal Resistance Junction to Ambient	80	°C/W	
wt	Approximate Weight	0.10(0.003)	g(oz.)	
	Case Style	SMB		Similar DO-214AA
	Device Marking	IR1J		

 $\binom{*}{dTj} \frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

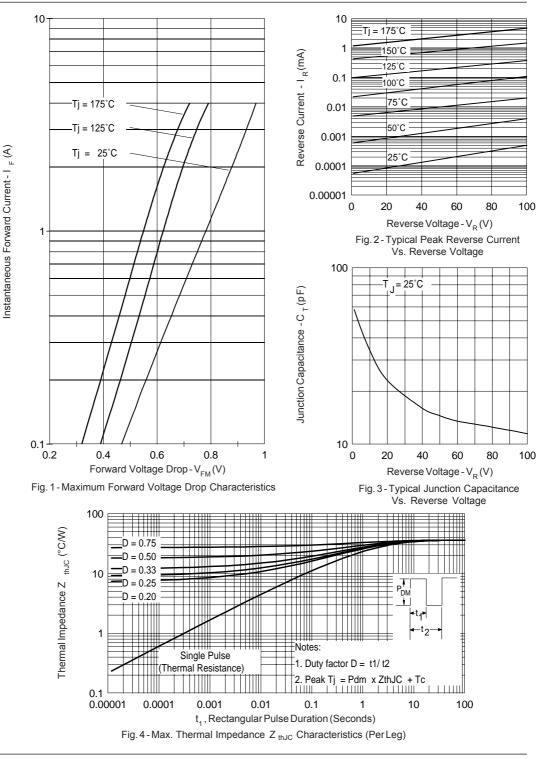
(**) Mounted 1 inch square PCB

Document Number: 94114

International **tor** Rectifier

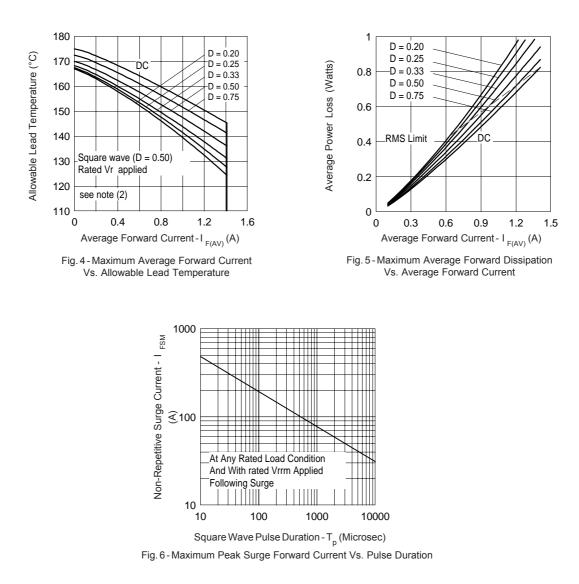
10BQ100PbF

Bulletin PD-20786 rev. A 07/04



Document Number: 94114

Bulletin PD-20786 rev. A 07/04

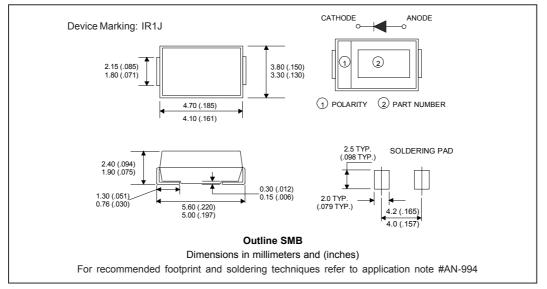


(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward Power Loss = I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6); $Pd_{REV} = Inverse Power Loss = V_{R1} \times I_R (1-D); I_R @ V_{R1} = 80\% rated V_R$

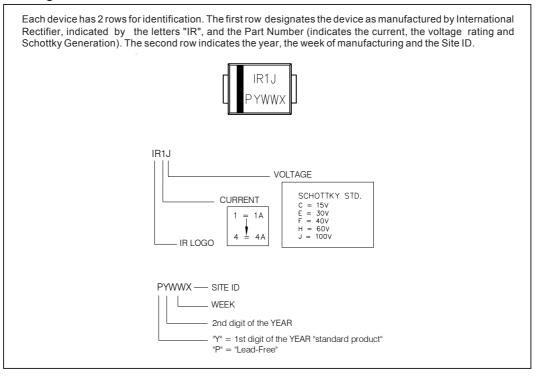
Document Number: 94114

Bulletin PD-20786 rev. A 07/04

Outline Table



Marking & Identification



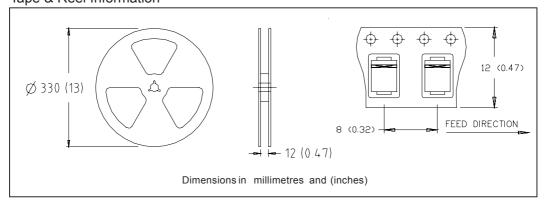
Document Number: 94114

10BQ100PbF

International

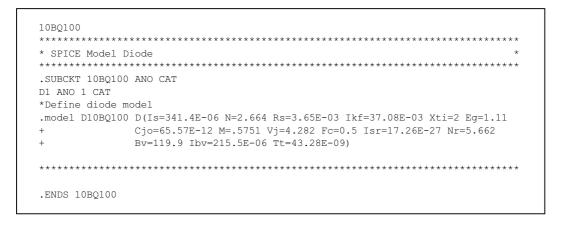
Tape & Reel Information

Bulletin PD-20786 rev. A 07/04



Ordering Information Table

Device Code	10 B Q 100 TR PbF
	1 2 3 4 5 6
	 Current Rating B = Single Lead Diode
	 3 - Q = Schottky Q Series 4 - Voltage Rating (100 = 100V)
	 • none = Box (1000 pieces) • TR = Tape & Reel (3000 pieces)
	 6 - • none = Standard Production • PbF = Lead-Free



Document Number: 94114

International	10BQ100PbF
TOR Rectifier	Bulletin PD-20786 rev. A 07/04

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level and Lead-Free. Qualification Standards can be found on IR's Web site.

International

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105 TAC Fax: (310) 252-7309 07/04

> www.vishay.com 7

Document Number: 94114



Vishay

Notice

The products described herein were acquired by Vishay Intertechnology, Inc., as part of its acquisition of International Rectifier's Power Control Systems (PCS) business, which closed in April 2007. Specifications of the products displayed herein are pending review by Vishay and are subject to the terms and conditions shown below.

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.

International Rectifier[®], IR[®], the IR logo, HEXFET[®], HEXSense[®], HEXDIP[®], DOL[®], INTERO[®], and POWIRTRAIN[®] are registered trademarks of International Rectifier Corporation in the U.S. and other countries. All other product names noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)